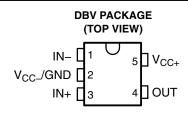
SLCS128F - APRIL 1996 - REVISED JUNE 2007

- Low-Voltage and Single-Supply Operation
 V_{CC} = 2 V to 7 V
- Common-Mode Voltage Range Includes Ground
- Fast Response Time . . . 0.7 μs Typ
- Low Supply Current . . . 80 μA Typ and 150 μA Max
- Fully Specified at 3-V and 5-V Supply Voltages



description/ordering informaton

The TLV1391 is a differential comparator built using a Texas Instruments low-voltage, high-speed bipolar process. These devices have been developed specifically for low-voltage, single-supply applications. Their enhanced performance makes them excellent replacements for the LM393 in the improved 3-V and 5-V system designs.

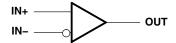
The TLV1391, with its typical supply current of only 80 μ A, is ideal for low-power systems. Response time also has been improved to 0.7 μ s.

ORDERING INFORMATION

| T _A | PACKAGE | <u>:</u> † | ORDERABLE PART NUMBER | TOP-SIDE MARKING [‡] |
|----------------|-----------------|--------------|--------------------------|----------------------------------|
| 000 to 7000 | COT OO F (DD)/\ | Reel of 3000 | TLV1391CDBVR | Van |
| −0°C to 70°C | SOT-23-5 (DBV) | Reel of 250 | TLV1391CDBVT | Y3D_ |
| 4000 to 0500 | COT OO F (DD)/\ | Reel of 3000 | TLV1391IDBVR | Voc |
| –40°C to 85°C | SOT-23-5 (DBV) | Reel of 250 | TLV1391IDBVT | Y3E_ |

[†] Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.

symbol (each comparator)



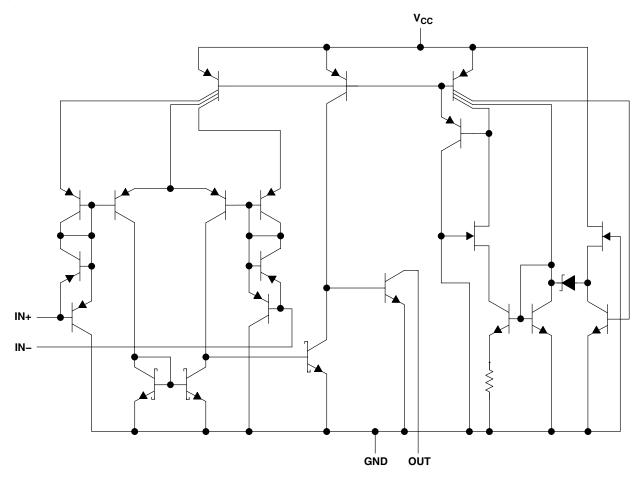


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



[‡] The actual top-side marking has one additional character that designates the wafer fab/assembly site.

equivalent schematic



| COMPONENT | COUNT |
|-------------|-------|
| Transistors | 26 |
| Resistors | 1 |
| Diodes | 4 |
| Epi-FET | 1 |



TLV1391 SINGLE DIFFERENTIAL COMPARATORS

SLCS128F - APRIL 1996 - REVISED JUNE 2007

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage, V _{CC} (see Note 1) | 7 V |
|--|---------------------------|
| Differential input voltage, V _{ID} (see Note 2) | ±7 V |
| Input voltage range, V _I (any input) | –0.3 V to V _{CC} |
| Output voltage, V _O | 7 V |
| Output current, I _O (each output) | 20 mA |
| Duration of short-circuit current to GND (see Note 3) | Unlimited |
| Package thermal impedance, θ_{JA} (see Note 4 and 5) | 206°C/W |
| Operating virtual junction temperature, T _J | 150°C |
| Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds | 260°C |
| Storage temperature range, T _{stg} | –65°C to 150°C |

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. All voltage values, except differential voltages, are with respect to the network GND.
 - 2. Differential voltages are at the noninverting input with respect to the inverting input.
 - 3. Short circuits from the outputs to V_{CC} can cause excessive heating and eventual destruction of the chip.
 - 4. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can impact reliability.
 - 5. The package thermal impedance is calculated in accordance with JESD 51-7.

recommended operating conditions

| | | | MIN | MAX | UNIT |
|-----------------|--------------------------------|------|-----|-----|------|
| V _{CC} | Supply voltage | | 2 | 7 | V |
| _ | Operating free-air temperature | 391C | 0 | 70 | 00 |
| 1A | TLV13 | 3911 | -40 | 85 | °C |



TLV1391 SINGLE DIFFERENTIAL COMPARATORS

SLCS128F - APRIL 1996 - REVISED JUNE 2007

electrical characteristics, $V_{CC} = 3 V$

| | PARAMETER | TEST | CONDITIONS | T _A | MIN | TYP | MAX | UNIT | |
|--|---------------------------------|-----------------------|-------------------------|----------------|------------------------------|------------------------------|------|------|--|
| V | loon it offert welleng | V 44V | V V (min) | 25°C | | 1.5 | 5 | \/ | |
| V_{IO} | Input offset voltage | $V_0 = 1.4 V,$ | $V_{IC} = V_{ICR}(min)$ | Full range | | | 9 | mV | |
| V _{ICR} Common-mode input voltage range | | | | 25°C | 0 to V _{CC} -1.5 | 0 to V _{CC} -1.2 | | V | |
| | Common-mode input voltage range | | | Full range | 0 to V _{CC} -2 | | | V | |
| V_{OL} | Low-level output voltage | $V_{ID} = -1 V$, | $I_{OL} = 500 \mu A$ | Full range | | 120 | 300 | mV | |
| | Input offset current | V 44V | | 25°C | | 5 | 50 | A | |
| I _{IO} | | $V_0 = 1.4 \text{ V}$ | | Full range | | | 150 | nA | |
| | | V 44V | | 25°C | | -40 | -250 | | |
| I _{IB} | Input bias current | $V_0 = 1.4 \text{ V}$ | | Full range | | | -400 | nA | |
| | | $V_{ID} = 1 V$, | V _{OH} = 3 V | 25°C | | 0.1 | | | |
| Іон | High-level output current | $V_{ID} = 1 V$, | V _{OH} = 5 V | Full range | | | 100 | nA | |
| l _{OL} | Low-level output current | $V_{ID} = -1 V$, | V _{OL} = 1.5 V | 25°C | 500 | | | μΑ | |
| | | ,, ,, | | 25°C | | 80 | 125 | | |
| I _{CC(H)} | High-level supply current | $V_O = V_{OH}$ | | Full range | | | 150 | μΑ | |
| | Low level cumply current | $V_O = V_{OL}$ | | 25°C | | 80 | 125 | 54 | |
| I _{CC(L)} | Low-level supply current | | | Full range | | | 150 | μΑ | |

switching characteristics, V_{CC} = 3 V, C_L = 15 pF $^\dagger,\,T_A$ = 25 $^\circ C$

| PARAMETER | TEST CONDITION | DNS | TYP | UNIT |
|---------------|--|-----------------------------|-----|------|
| Response time | 100-mV input step with 5-mV overdrive, | $R_L = 5.1 \text{ k}\Omega$ | 0.7 | μs |

[†] C_L includes the probe and jig capacitance.



electrical characteristics, $V_{CC} = 5 V$

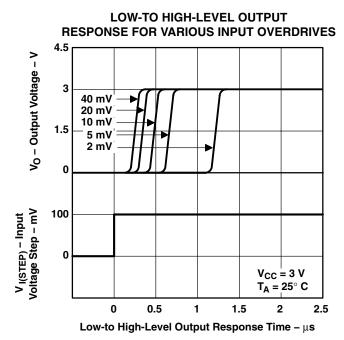
| | PARAMETER | TEST | CONDITIONS | T _A | MIN | TYP | MAX | UNIT | |
|---------------------------------------|--------------------------------------|-----------------------|-------------------------|----------------|------------------------------|------------------------------|------|------|-----|
| \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | land offertualtens | V 44V | V V (main) | 25°C | | 1.5 | 5 | \/ | |
| V _{IO} | Input offset voltage | $V_0 = 1.4 V,$ | $V_{IC} = V_{ICR}(min)$ | Full range | | | 9 | mV | |
| V | Common mode input voltage years | | | 25°C | 0 to V _{CC} -1.5 | 0 to V _{CC} -1.2 | | V | |
| V _{ICR} | Common-mode input voltage range | | | Full range | 0 to V _{CC} -2 | | | V | |
| V_{OL} | Low-level output voltage | $V_{ID} = -1 V$, | $I_{OL} = 500 \mu A$ | Full range | | 120 | 300 | mV | |
| l . | I _{IO} Input offset current | Input offset surrent | | 4.4.1/ | | | 5 | 50 | - A |
| IO | | $V_0 = 1.4 \text{ V}$ | | Full range | | | 150 | nA | |
| | land the amount | V 44V | | 25°C | | -40 | -250 | A | |
| I _{IB} | Input bias current | $V_0 = 1.4 \text{ V}$ | | Full range | | | -400 | nA | |
| | LEab land autout annual | $V_{ID} = 1 V$, | V _{OH} = 3 V | 25°C | | 0.1 | | A | |
| Іон | High-level output current | $V_{ID} = 1 V$, | V _{OH} = 5 V | Full range | | | 100 | nA | |
| I _{OL} | Low-level output current | $V_{ID} = -1 V$, | V _{OL} = 1.5 V | 25°C | 600 | | | μΑ | |
| | High level events events | V V | | 25°C | | 100 | 150 | | |
| I _{CC(H)} | High-level supply current | $V_O = V_{OH}$ | | Full range | | | 175 | μΑ | |
| | Low lovel cumby cumont | V V | | 25°C | | 100 | 150 | | |
| I _{CC(L)} | Low-level supply current | $V_O = V_{OL}$ | | Full range | | | 175 | μΑ | |

switching characteristics, V_{CC} = 5 V, C_L = 15 pF†, T_A = 25°C

| PARAMETER | TEST CONDITIONS | | TYP | UNIT |
|---------------|--|-----------------------------|------|------|
| Deenenes time | 100-mV input step with 5-mV overdrive, | $R_L = 5.1 \text{ k}\Omega$ | 0.65 | |
| Response time | TTL-level input step, | $R_L = 5.1 \text{ k}\Omega$ | 0.18 | μs |

[†] C_L includes the probe and jig capacitance.

TYPICAL CHARACTERISTICS





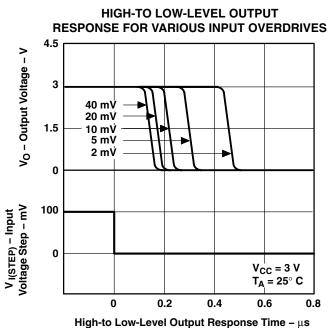


Figure 2

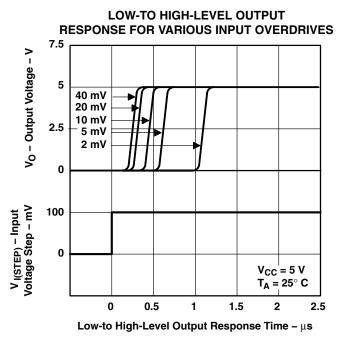


Figure 3

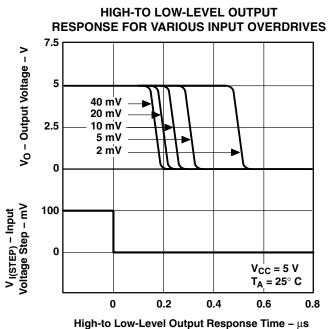


Figure 4





10-Dec-2020

PACKAGING INFORMATION

| Orderable Device | Status | Package Type | _ | Pins | _ | Eco Plan | Lead finish/ | MSL Peak Temp | Op Temp (°C) | Device Marking | Samples |
|------------------|--------|--------------|---------|------|------|--------------|-------------------|--------------------|--------------|--------------------|---------|
| | (1) | | Drawing | | Qty | (2) | Ball material (6) | (3) | | (4/5) | |
| TLV1391CDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | (Y3D6, Y3DG, Y3DJ) | Samples |
| TLV1391CDBVRG4 | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU | Level-1-260C-UNLIM | 0 to 70 | Y3DG | Samples |
| TLV1391CDBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | 0 to 70 | (Y3DB, Y3DG, Y3DJ) | Samples |
| TLV1391IDBVR | ACTIVE | SOT-23 | DBV | 5 | 3000 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | (Y3E6, Y3EB, Y3EJ) | Samples |
| TLV1391IDBVT | ACTIVE | SOT-23 | DBV | 5 | 250 | RoHS & Green | NIPDAU SN | Level-1-260C-UNLIM | -40 to 85 | (Y3EB, Y3EJ) | Samples |

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.



PACKAGE OPTION ADDENDUM

10-Dec-2020

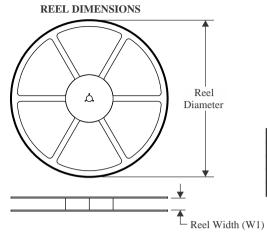
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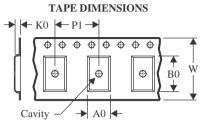
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TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| TLV1391CDBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.3 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV1391CDBVRG4 | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.23 | 3.17 | 1.37 | 4.0 | 8.0 | Q3 |
| TLV1391CDBVT | SOT-23 | DBV | 5 | 250 | 178.0 | 9.0 | 3.3 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV1391IDBVR | SOT-23 | DBV | 5 | 3000 | 178.0 | 9.0 | 3.3 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV1391IDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 8.4 | 3.2 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |
| TLV1391IDBVT | SOT-23 | DBV | 5 | 250 | 178.0 | 9.0 | 3.3 | 3.2 | 1.4 | 4.0 | 8.0 | Q3 |



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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| TLV1391CDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TLV1391CDBVRG4 | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TLV1391CDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |
| TLV1391IDBVR | SOT-23 | DBV | 5 | 3000 | 180.0 | 180.0 | 18.0 |
| TLV1391IDBVT | SOT-23 | DBV | 5 | 250 | 203.0 | 203.0 | 35.0 |
| TLV1391IDBVT | SOT-23 | DBV | 5 | 250 | 180.0 | 180.0 | 18.0 |



SMALL OUTLINE TRANSISTOR



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
 2. This drawing is subject to change without notice.
 3. Refernce JEDEC MO-178.

- 4. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25 mm per side.
- 5. Support pin may differ or may not be present.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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